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TECHNICAL DATA SHEET

NPN POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/394

ELECTRICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise noted) (CONT.)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Collector-Base Cutoff Current $V_{CB} = 100\text{Vdc}$ 2N4150, 2N4150S $V_{CB} = 150\text{Vdc}$ 2N5237, 2N5237S $V_{CB} = 200\text{Vdc}$ 2N5238, 2N5238S $V_{CB} = 80\text{Vdc}$ All Types	I_{CBO}		10 10 10 0.1	$\mu\text{A dc}$
ON CHARACTERISTICS ⁽³⁾				
Forward-Current Transfer Ratio $I_C = 1.0\text{A dc}$, $V_{CE} = 5.0\text{Vdc}$ 2N4150, 2N4150S 2N5237, 2N5237S 2N5238, 2N5238S $I_C = 5.0\text{A dc}$, $V_{CE} = 5.0\text{Vdc}$ All Types $I_C = 10\text{A dc}$, $V_{CE} = 5.0\text{Vdc}$ All Types	h_{FE}	50 50 50 40 10	200 225 225 120 -	
Collector-Emitter Saturation Voltage $I_C = 5.0\text{A dc}$, $I_B = 0.5\text{A dc}$ $I_C = 10\text{A dc}$, $I_B = 1.0\text{A dc}$	$V_{CE(sat)}$		0.6 2.5	Vdc
Base-Emitter Saturation Voltage $I_C = 5.0\text{A dc}$, $I_B = 0.5\text{A dc}$ $I_C = 10\text{A dc}$, $I_B = 1.0\text{A dc}$	$V_{BE(sat)}$		1.5 25	Vdc

DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio $I_C = 0.2\text{A dc}$, $V_{CE} = 10\text{Vdc}$, $f = 10\text{MHz}$	$ h_{fe} $	1.5	7.5	
Forward Current Transfer Ratio $I_C = 50\text{mA dc}$, $V_{CE} = 5.0\text{V}$, $f = 1.0\text{kHz}$ 2N4150, 2N4150S 2N5237, 2N5237S 2N5238, 2N5238S	h_{fe}	40 40 40	160 160 250	
Output Capacitance $V_{CB} = 10\text{Vdc}$, $I_E = 0$, $100\text{kHz} \leq f \leq 1.0\text{MHz}$	C_{obo}		350	pF

SWITCHING CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Delay Time $V_{CC} = 20\text{Vdc}$, $V_{BB} = 5.0\text{Vdc}$	t_d		50	ns
Rise Time $I_C = 5.0\text{A dc}$, $I_{B1} = 0.5\text{A dc}$	t_r		500	ns
Storage Time $V_{CC} = 20\text{Vdc}$, $V_{BB} = 5.0\text{Vdc}$	t_s		1.5	μs
Fall Time $I_C = 5.0\text{A dc}$, $I_{B1} = -I_{B2} = -0.5\text{A dc}$	t_f		500	ns

SAFE OPERATING AREA

DC Tests $T_C = +25^\circ\text{C}$, 1 Cycle, $t = 1.0\text{s}$ Test 1 $V_{CE} = 40\text{Vdc}$, $I_C = 0.22\text{A dc}$ Test 2 $V_{CE} = 70\text{Vdc}$, $I_C = 90\text{mA dc}$ Test 3 $V_{CE} = 120\text{Vdc}$, $I_C = 15\text{mA dc}$ 2N5237, 2N5237S $V_{CE} = 170\text{Vdc}$, $I_C = 3.5\text{mA dc}$ 2N5238, 2N5238S				
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(3) Pulse Test: Pulse Width = $300\mu\text{s}$, Duty Cycle $\leq 2.0\%$